



**THE DATASHEET OF
MC100EP139MNG**



3.3 V/5 V ECL $\div 2/4$, $\div 4/5/6$ Clock Generation Chip

MC10EP139, MC100EP139

Description

The MC10/100EP139 is a low skew $\div 2/4$, $\div 4/5/6$ clock generation chip designed explicitly for low skew clock generation applications. The internal dividers are synchronous to each other, therefore, the common output edges are all precisely aligned.

The common enable (\overline{EN}) is synchronous so that the internal dividers will only be enabled/disabled when the internal clock is already in the LOW state. This avoids any chance of generating a runt clock pulse on the internal clock when the device is enabled/disabled as can happen with an asynchronous control. The internal enable flip-flop is clocked on the falling edge of the input clock, therefore, all associated specification limits are referenced to the negative edge of the clock input.

Upon start-up, the internal flip-flops will attain a random state; therefore the master reset (MR) input may require assertion to ensure system synchronization. Internal divider design ensures synchronization between the $\div 2/4$ and the $\div 4/5/6$ outputs within a device. All V_{CC} and V_{EE} pins must be externally connected to power supply to guarantee proper operation.

The V_{BB} Pin, an internally generated voltage supply, is available to this device only. For Single-Ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

The 100 Series contains temperature compensation.

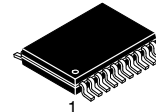
Features

- Maximum Frequency = > 1.0 GHz Typical
- 50 ps Output-to-Output Skew
- PECL Mode Operating Range:
 $V_{CC} = 3.0 V$ to $5.5 V$ with $V_{EE} = 0 V$
- NECL Mode Operating Range:
 $V_{CC} = 0 V$ with $V_{EE} = -3.0 V$ to $-5.5 V$
- Open Input Default State
- Safety Clamp on Inputs
- Synchronous Enable/Disable
- Master Reset for Synchronization of Multiple Chips
- V_{BB} Output
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

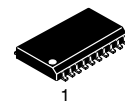


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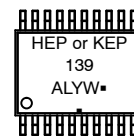


TSSOP-20 WB
DT SUFFIX
CASE 948E

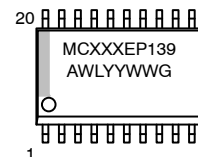


SOIC-20 WB
DW SUFFIX
CASE 751D

MARKING DIAGRAMS*



TSSOP-20 WB



SOIC-20 WB

- HEP = MC10EP
- KEP = MC100EP
- XXX = 10 or 100
- A = Assembly Location
- L, WL = Wafer Lot
- Y, YY = Year
- W, WW = Work Week
- G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

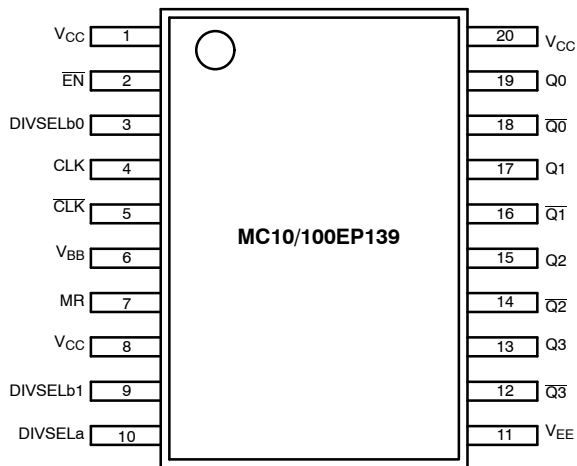
*For additional marking information, refer to Application Note [AND8002/D](#).

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------------|-----------------------|--------------------|
| MC10EP139DTG | TSSOP-20 WB (Pb-Free) | 75 Units / Tube |
| MC100EP139DTG | TSSOP-20 WB (Pb-Free) | 75 Units / Tube |
| MC100EP139DTR2G | TSSOP-20 WB (Pb-Free) | 2500 / Tape & Reel |
| MC100EP139DWG | TSSOP-20 WB (Pb-Free) | 38 Units / Tube |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

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Warning: All V_{CC} and V_{EE} pins must be externally connected to a Power Supply to guarantee proper operation.

Figure 1. 20-Lead Pinout (Top View)

Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
|---|---|
| CLK*, $\overline{\text{CLK}}^*$ | ECL Differential Clock Inputs |
| EN* | ECL Sync Enable |
| MR* | ECL Master Reset |
| V_{BB} | ECL Reference Output |
| Q0, Q1, $\overline{Q0}$, $\overline{Q1}$ | ECL Differential $\div 2/4$ Outputs |
| Q2, Q3, $\overline{Q2}$, $\overline{Q3}$ | ECL Differential $\div 4/5/6$ Outputs |
| DIVSELa* | ECL Frequency Select Input $\div 2/4$ |
| DIVSELb0* | ECL Frequency Select Input $\div 4/5/6$ |
| DIVSELb1* | ECL Frequency Select Input $\div 4/5/6$ |
| V_{CC} | ECL Positive Supply |
| V_{EE} | ECL Negative Supply |

*Pins will default low when left open.

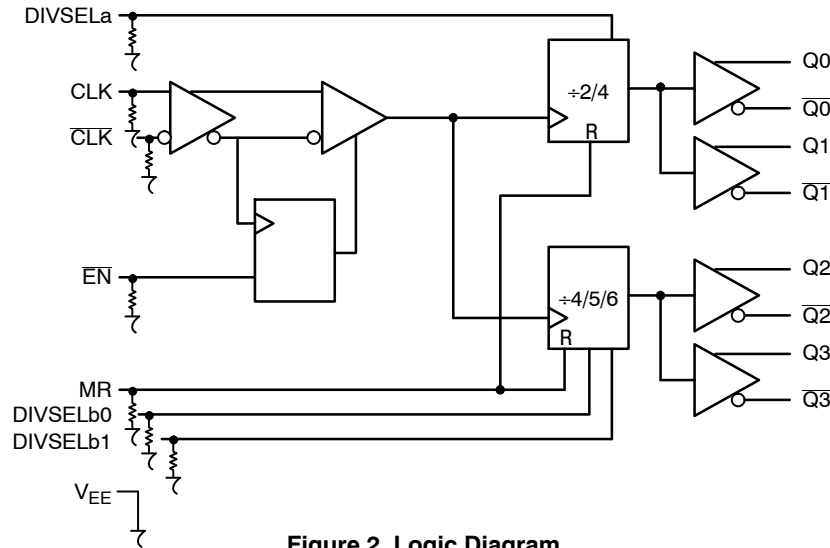


Figure 2. Logic Diagram

Table 2. FUNCTION TABLES

| CLK | EN | MR | Function |
|-----|----|----|------------|
| Z | L | L | Divide |
| ZZ | H | L | Hold Q0:3 |
| X | X | H | Reset Q0:3 |

Z = Low-to-High Transition
ZZ = High-to-Low Transition

| DIVSELa | Q0:1 Outputs | |
|----------|--------------|--------------|
| L | Divide by 2 | |
| H | Divide by 4 | |
| DIVSELb0 | DIVSELb1 | Q2:3 Outputs |
| L | L | Divide by 4 |
| H | L | Divide by 6 |
| L | H | Divide by 5 |
| H | H | Divide by 5 |

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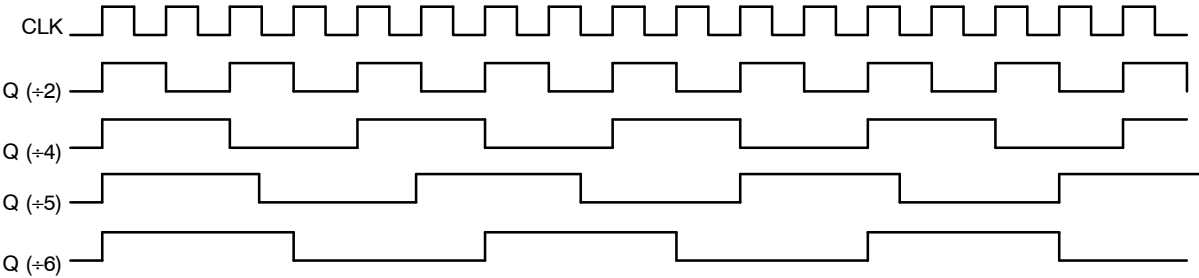


Figure 3. CLK and OUTPUT Timing Diagram

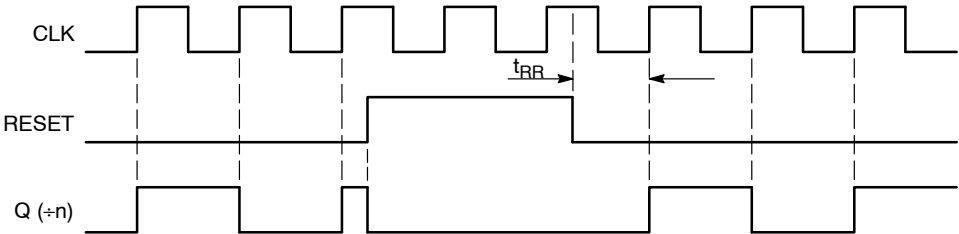


Figure 4. Timing Diagram

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Table 3. ATTRIBUTES

| Characteristics | Value |
|---|-----------------------------|
| Internal Input Pulldown Resistor | 75 kΩ |
| Internal Input Pullup Resistor | N/A |
| ESD Protection Human Body Model Machine Model Charged Device Model | > 2 kV > 100 V > 2 kV |
| Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1) | Pb-Free Pkg |
| SOIC–20 WB TSSOP–20 W | Level 3 Level 1 |
| Flammability Rating Oxygen Index: 28 to 34 | UL 94 V–0 @ 0.125 in |
| Transistor Count | 758 Devices |
| Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test | |

1. For additional information, see Application Note [AND8003/D](#).

Table 4. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
|------------------|--|--|--|-------------|------|
| V _{CC} | PECL Mode Power Supply | V _{EE} = 0 V | | 6 | V |
| V _{EE} | NECL Mode Power Supply | V _{CC} = 0 V | | –6 | V |
| V _I | PECL Mode Input Voltage NECL Mode Input Voltage | V _{EE} = 0 V V _{CC} = 0 V | V _I ≤ V _{CC} V _I ≥ V _{EE} | 6 –6 | V |
| I _{out} | Output Current | Continuous Surge | | 50 100 | mA |
| I _{BB} | V _{BB} Sink/Source | | | ±0.5 | mA |
| T _A | Operating Temperature Range | | | –40 to +85 | °C |
| T _{stg} | Storage Temperature Range | | | –65 to +150 | °C |
| θ _{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | TSSOP–20 WB TSSOP–20 WB | 140 100 | °C/W |
| θ _{JC} | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP–20 WB | 23 to 41 | °C/W |
| θ _{JA} | Thermal Resistance (Junction-to-Ambient) | 0 lfpm 500 lfpm | SOIC–20 WB SOIC–20 WB | 90 60 | °C/W |
| θ _{JC} | Thermal Resistance (Junction-to-Case) | Standard Board | SOIC–20 WB | 33 to 35 | °C/W |
| T _{sol} | Wave Solder (Pb-Free) | < 2 to 3 sec @ 260°C | | 265 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

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Table 5. 10EP DC CHARACTERISTICS, PECL ($V_{CC} = 3.3\text{ V}$, $V_{EE} = 0\text{ V}$ (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 65 | 82 | 105 | 65 | 83 | 105 | 65 | 84 | 105 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | 2165 | 2290 | 2415 | 2230 | 2355 | 2480 | 2290 | 2415 | 2540 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | 1365 | 1490 | 1615 | 1430 | 1555 | 1680 | 1490 | 1615 | 1740 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | 2090 | | 2415 | 2155 | | 2480 | 2215 | | 2540 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | 1365 | | 1690 | 1460 | | 1755 | 1490 | | 1815 | mV |
| V_{BB} | Output Voltage Reference | 1790 | 1890 | 1990 | 1855 | 1955 | 2055 | 1915 | 2015 | 2115 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0 | | 3.3 | 2.0 | | 3.3 | 2.0 | | 3.3 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.3 V to -2.2 V.
2. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 6. 10EP DC CHARACTERISTICS, PECL ($V_{CC} = 5.0\text{ V}$, $V_{EE} = 0\text{ V}$ (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 65 | 82 | 105 | 65 | 83 | 105 | 65 | 84 | 105 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | 3865 | 3990 | 4115 | 3930 | 4055 | 4180 | 3990 | 4115 | 4240 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | 3065 | 3190 | 3315 | 3130 | 3255 | 3380 | 3190 | 3315 | 3440 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | 3790 | | 4115 | 3855 | | 4180 | 3915 | | 4240 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | 3065 | | 3390 | 3130 | | 3455 | 3190 | | 3515 | mV |
| V_{BB} | Output Voltage Reference | 3490 | 3590 | 3690 | 3555 | 3655 | 3755 | 3615 | 3715 | 3815 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0 | | 5.0 | 2.0 | | 5.0 | 2.0 | | 5.0 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +2.0 V to -0.5 V.
2. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

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Table 7. 10EP DC CHARACTERISTICS, NECL ($V_{CC} = 0\text{ V}$, $V_{EE} = -5.5\text{ V}$ to -3.0 V (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|--------------|-------|-------|--------------|-------|-------|--------------|-------|-------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 65 | 82 | 105 | 65 | 83 | 105 | 65 | 84 | 105 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | -1135 | -1010 | -885 | -1070 | -945 | -820 | -1010 | -885 | -760 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | -1935 | -1810 | -1685 | -1870 | -1745 | -1620 | -1810 | -1685 | -1560 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | -1210 | | -885 | -1145 | | -820 | -1085 | | -760 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | -1935 | | -1610 | -1870 | | -1545 | -1810 | | -1485 | mV |
| V_{BB} | Output Voltage Reference | -1510 | -1410 | -1310 | -1445 | -1345 | -1245 | -1385 | -1285 | -1185 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | $V_{EE}+2.0$ | | 0.0 | $V_{EE}+2.0$ | | 0.0 | $V_{EE}+2.0$ | | 0.0 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with V_{CC} .
2. All loading with $50\ \Omega$ to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 8. 100EP DC CHARACTERISTICS, PECL ($V_{CC} = 3.3\text{ V}$, $V_{EE} = 0\text{ V}$ (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 70 | 83 | 100 | 70 | 87 | 105 | 75 | 90 | 110 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | 2155 | 2280 | 2405 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | 1305 | 1480 | 1605 | 1305 | 1480 | 1605 | 1305 | 1480 | 1605 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | 2075 | | 2420 | 2075 | | 2420 | 2075 | | 2420 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | 1305 | | 1675 | 1305 | | 1675 | 1305 | | 1675 | mV |
| V_{BB} | Output Voltage Reference | 1725 | 1825 | 1925 | 1725 | 1825 | 1925 | 1725 | 1825 | 1925 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0 | | 3.3 | 2.0 | | 3.3 | 2.0 | | 3.3 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary $+0.3\text{ V}$ to -2.2 V .
2. All loading with $50\ \Omega$ to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

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Table 9. 100EP DC CHARACTERISTICS, PECL ($V_{CC} = 5.0\text{ V}$, $V_{EE} = 0\text{ V}$ (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|-------|------|------|------|------|------|------|------|------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 70 | 85 | 100 | 70 | 90 | 105 | 75 | 95 | 110 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | 3855 | 3980 | 4105 | 3855 | 3980 | 4105 | 3855 | 3980 | 4105 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | 3005 | 3180 | 3305 | 3005 | 3180 | 3305 | 3005 | 3180 | 3305 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | 3775 | | 4120 | 3775 | | 4120 | 3775 | | 4120 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | 3005 | | 3375 | 3005 | | 3375 | 3005 | | 3375 | mV |
| V_{BB} | Output Voltage Reference | 3425 | 3525 | 3625 | 3425 | 3525 | 3625 | 3425 | 3525 | 3625 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | 2.0 | | 5.0 | 2.0 | | 5.0 | 2.0 | | 5.0 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lpm.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +2.0 V to -0.5 V.
2. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

Table 10. 100EP DC CHARACTERISTICS, NECL ($V_{CC} = 0\text{ V}$, $V_{EE} = -5.5\text{ V}$ to -3.0 V (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|-------------|--|--------------|-------|-------|--------------|-------|-------|--------------|-------|-------|---------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| I_{EE} | Power Supply Current | 70 | 85 | 100 | 70 | 90 | 105 | 75 | 95 | 110 | mA |
| V_{OH} | Output HIGH Voltage (Note 2) | -1145 | -1020 | -895 | -1145 | -1020 | -895 | -1145 | -1020 | -895 | mV |
| V_{OL} | Output LOW Voltage (Note 2) | -1995 | -1820 | -1695 | -1995 | -1820 | -1695 | -1995 | -1820 | -1695 | mV |
| V_{IH} | Input HIGH Voltage (Single-Ended) | -1225 | | -880 | -1225 | | -880 | -1225 | | -880 | mV |
| V_{IL} | Input LOW Voltage (Single-Ended) | -1995 | | -1625 | -1995 | | -1625 | -1995 | | -1625 | mV |
| V_{BB} | Output Voltage Reference | -1575 | -1475 | -1375 | -1575 | -1475 | -1375 | -1575 | -1475 | -1375 | mV |
| V_{IHCMR} | Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 3) | $V_{EE}+2.0$ | | 0.0 | $V_{EE}+2.0$ | | 0.0 | $V_{EE}+2.0$ | | 0.0 | V |
| I_{IH} | Input HIGH Current | | | 150 | | | 150 | | | 150 | μA |
| I_{IL} | Input LOW Current | 0.5 | | | 0.5 | | | 0.5 | | | μA |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lpm.

1. Input and output parameters vary 1:1 with V_{CC} .
2. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
3. V_{IHCMR} min varies 1:1 with V_{EE} . V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

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Table 11. AC CHARACTERISTICS ($V_{CC} = 0\text{ V}$; $V_{EE} = -3.0\text{ V}$ to -5.5 V or $V_{CC} = 3.0\text{ V}$ to 5.5 V ; $V_{EE} = 0\text{ V}$ (Note 1))

| Symbol | Characteristic | -40°C | | | 25°C | | | 85°C | | | Unit |
|--------------------------|---|------------|------------|------------|------------|------------|-------------|------------|------------|-------------|------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | |
| f_{max} | Maximum Frequency (See Figures 5, 6, 7 and 8 F_{max} /JITTER) | | > 1 | | | > 1 | | | > 1 | | GHz |
| t_{PLH} , t_{PHL} | Propagation Delay CLK, Q (Diff) MR, Q | 550 700 | 700 800 | 800 900 | 600 700 | 750 850 | 900 1000 | 675 800 | 825 950 | 975 1100 | ps |
| t_{RR} | Reset Recovery | 200 | 100 | | 200 | 100 | | 200 | 100 | | ps |
| t_s | Setup Time EN, CLK DIVSEL, CLK | 200 400 | 120 180 | | 200 400 | 120 180 | | 200 400 | 120 180 | | ps |
| t_h | Hold Time $\overline{\text{CLK}}$, $\overline{\text{EN}}$ CLK, DIVSEL | 100 200 | 50 140 | | 100 200 | 50 140 | | 100 200 | 50 140 | | ps |
| t_{PW} | Minimum Pulse Width MR | 550 | 450 | | 550 | 450 | | 550 | 450 | | ps |
| t_{SKEW} | Within Device Skew Q, \overline{Q} Device-to-Device Skew (Note 2) | | 50 200 | 100 300 | | 50 200 | 100 300 | | 50 200 | 100 300 | ps |
| t_{JITTER} | Random Clock Jitter (RMS) (See Figures 5, 6, 7 and 8 F_{max} /JITTER) | | 0.2 | < 1.0 | | 0.2 | < 1.0 | | 0.2 | < 1.5 | ps |
| V_{PP} | Input Voltage Swing (Differential Configuration) | 150 | 800 | 1200 | 150 | 800 | 1200 | 150 | 800 | 1200 | mV |
| t_r t_f | Output Rise/Fall Times Q, \overline{Q} (20%–80%) | 110 | 180 | 250 | 125 | 190 | 275 | 150 | 215 | 300 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lpm.

1. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to $V_{CC} - 2.0\text{ V}$ (see Figure 9).
2. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

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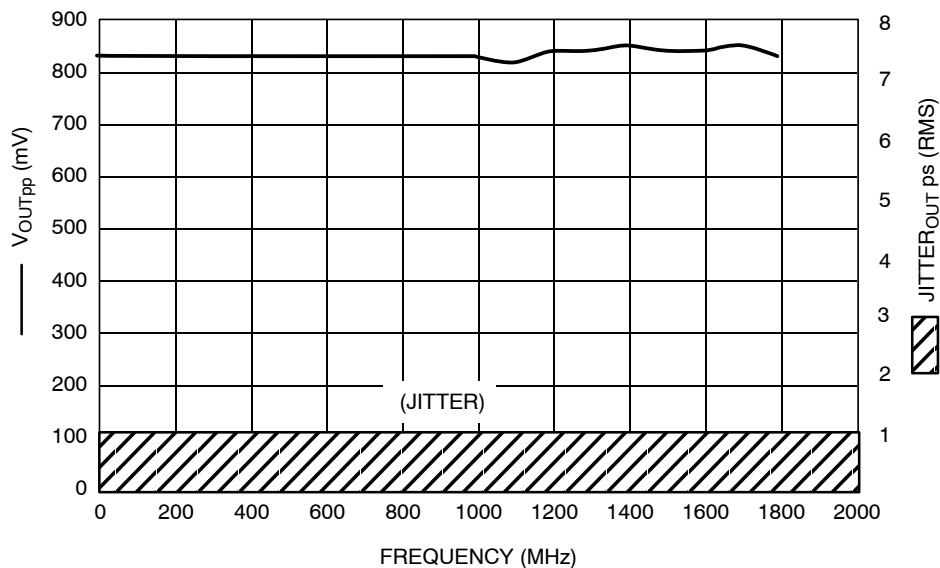


Figure 5. $\div 2$, F_{max}/Jitter

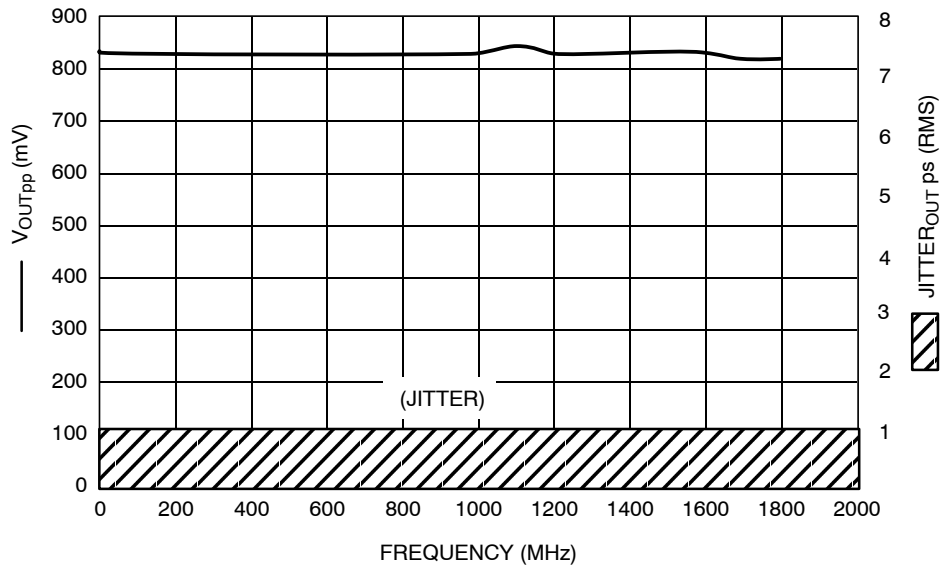


Figure 6. $\div 5$, F_{max}/Jitter

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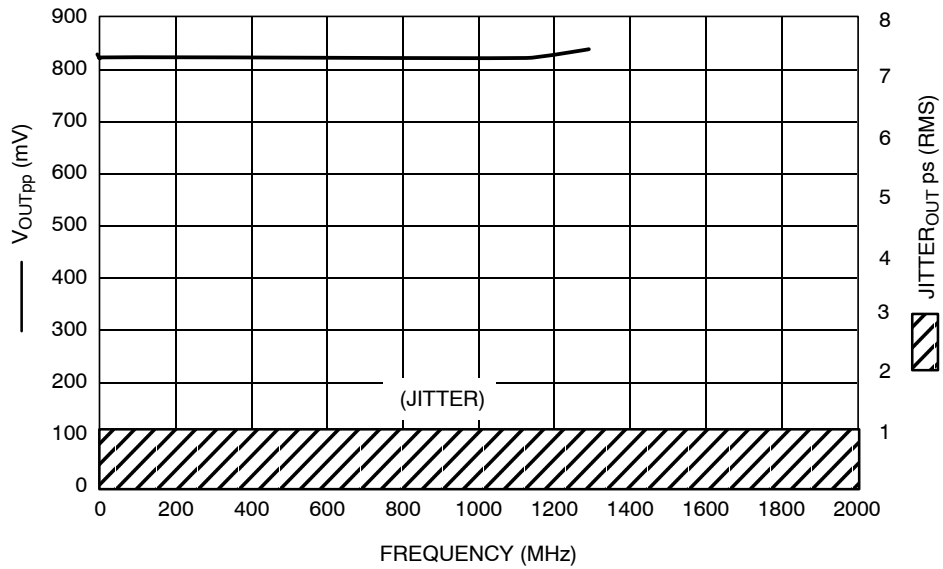


Figure 7. $\div 4$, $F_{max}/Jitter$

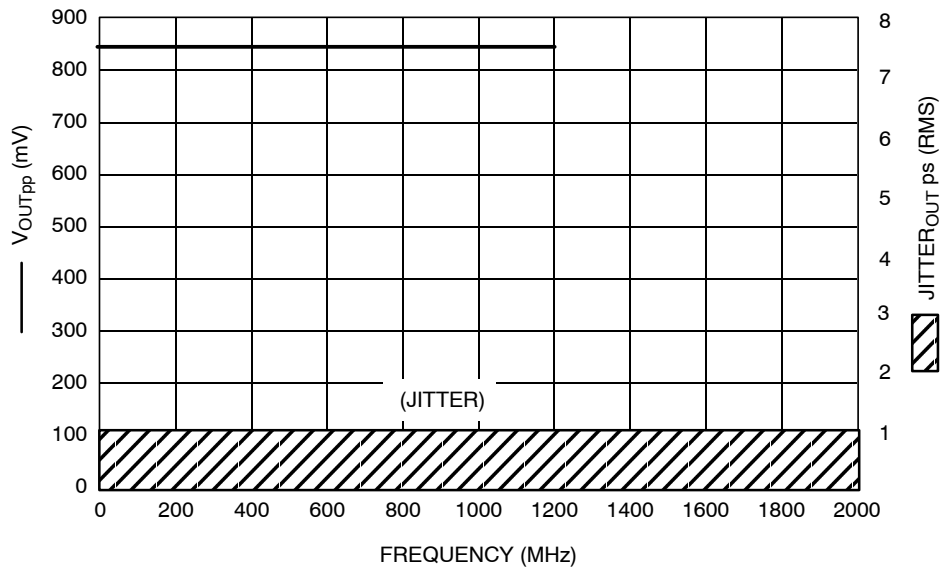


Figure 8. $\div 6$, $F_{max}/Jitter$

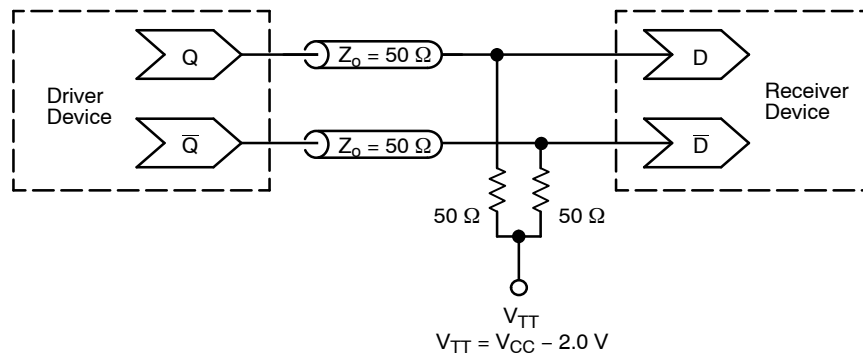


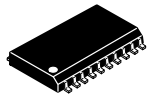
Figure 9. Typical Termination for Output Driver and Device Evaluation
(See Application Note [AND8020/D](#) – Termination of ECL Logic Devices)

MC10EP139, MC100EP139

Resource Reference of Application Notes

- AN1405/D** – ECL Clock Distribution Techniques
- AN1406/D** – Designing with PECL (ECL at +5.0 V)
- AN1503/D** – ECLinPS™ I/O SPiCE Modeling Kit
- AN1504/D** – Metastability and the ECLinPS Family
- AN1568/D** – Interfacing Between LVDS and ECL
- AN1672/D** – The ECL Translator Guide
- AND8001/D** – Odd Number Counters Design
- AND8002/D** – Marking and Date Codes
- AND8020/D** – Termination of ECL Logic Devices
- AND8066/D** – Interfacing with ECLinPS
- AND8090/D** – AC Characteristics of ECL Devices

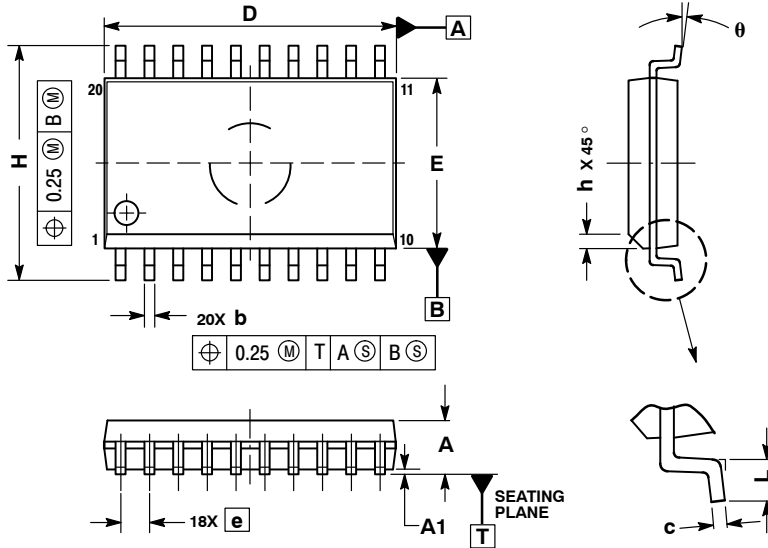
MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



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SOIC-20 WB
CASE 751D-05
ISSUE H

DATE 22 APR 2015

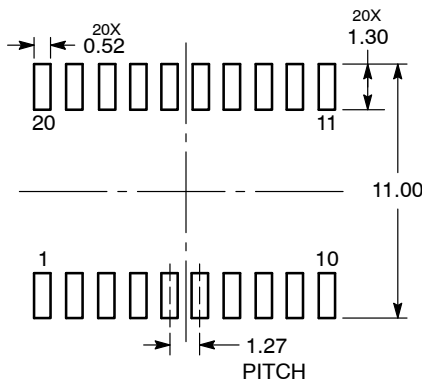


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| b | 0.35 | 0.49 |
| c | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC | |
| H | 10.05 | 10.55 |
| h | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| θ | 0° | 7° |

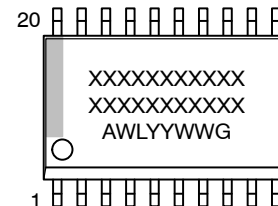
RECOMMENDED
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC
MARKING DIAGRAM*



- XXXXXX = Specific Device Code
- A = Assembly Location
- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

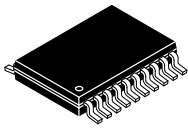
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

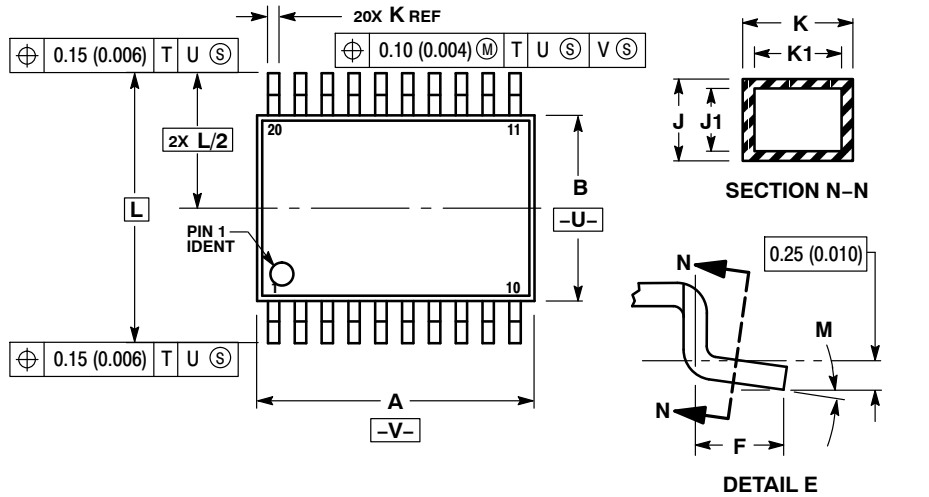
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CASE 948E
ISSUE D

DATE 17 FEB 2016

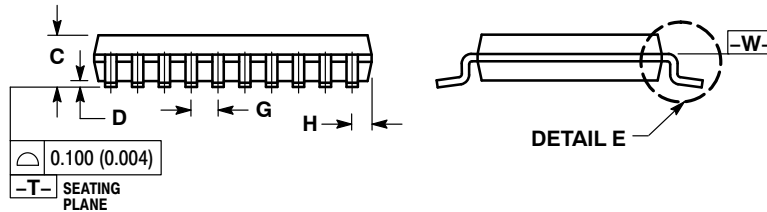
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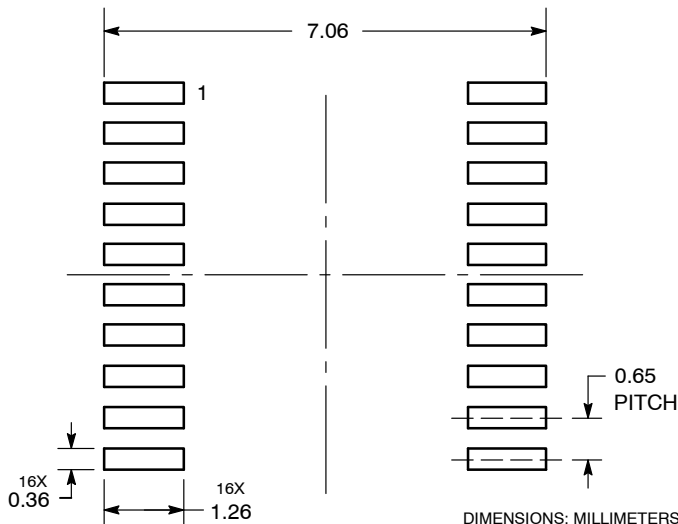
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

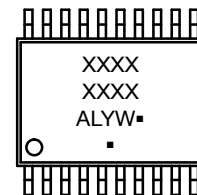
| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| M | 0° | 8° | 0° | 8° |



SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

| | | |
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